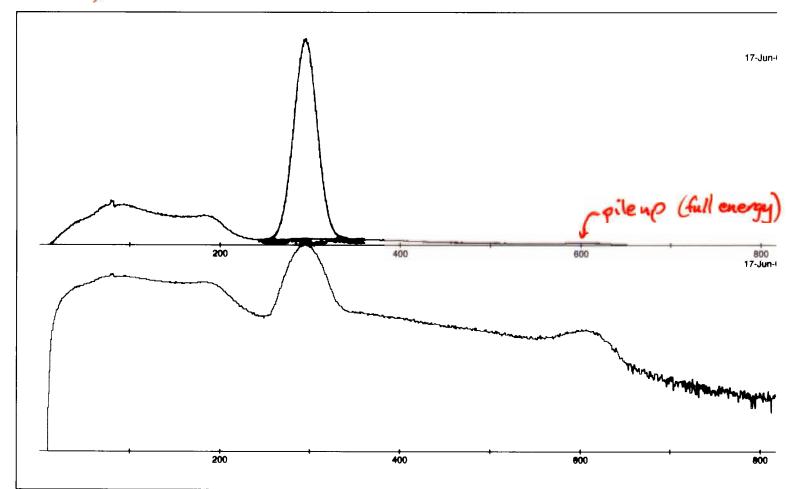
B7 Cs, Z=10 cm from face of NaI



Total Full Energy Counts = photopeak + 2x tullenergy pileup

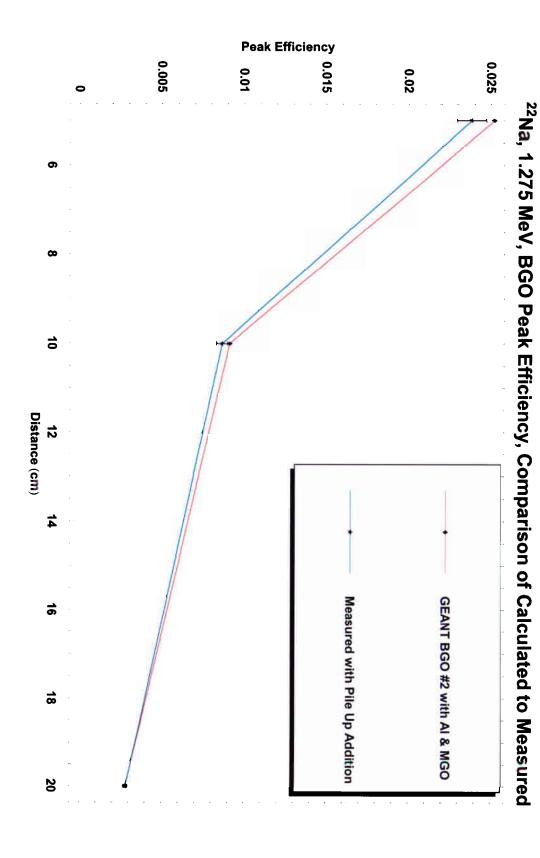
(\frac{1}{2} counts to -ight of peak

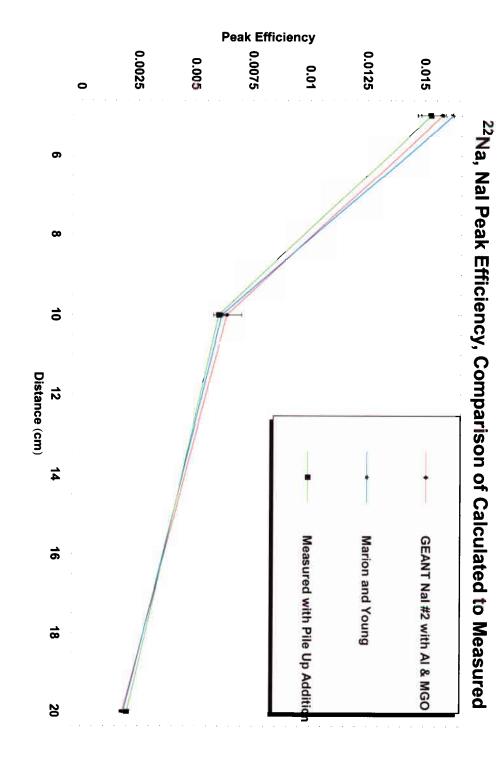
- full energy pile up)

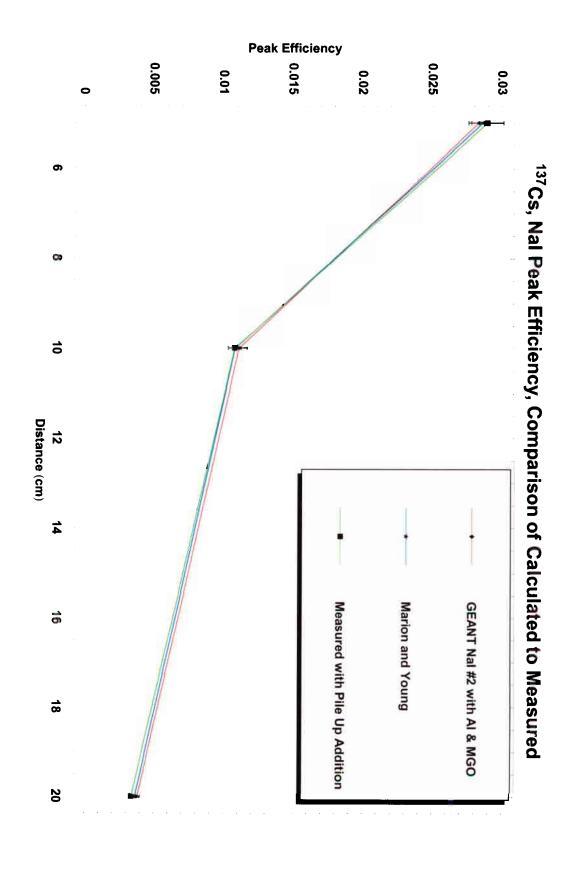
Gamma Efficiency Simulation

and Measurement

- sources of error in data
- fit errors
- source activity tolerance (1576, 54 75.7%)
- sources of error in simulation
- tolerances in the dimensions of detector
- reflector thickness
- aluminum dimensions







and Measurement Gamma Efficiency Simulation

- AmBe (4.44 MeV) results
- source strength
- 28533 γ/s (NaI GEANT cross calibration)
- 31219 γ/s (NaI Marion cross calibration)
- 33144 γ/s (10% error) (Croft **b** to n⁰ ratio)

and Measurement Gamma Efficiency Simulation

- BGO photopeak efficiency of a single crystal **measured** to be:
- 0.00132 (NaI GEANT cross calibration)
- 0.00121 (NaI Marion cross calibration)
- -0.00113 (10% error) (Croft 4 to n^{0} ratio)
- BGO photopeak efficiency of a single crystal simulated to be:
- 0.00131 (GEANT simulation)